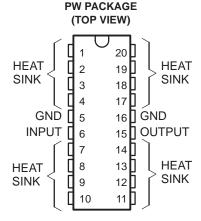
- Fully Matches Parameters for SCSI Alternative 2 Active Termination
- Fixed 2.85-V Output
- ±1.5% Maximum Output Tolerance at T_J = 25°C
- 1-V Maximum Dropout Voltage
- 500-mA Output Current
- ±3% Absolute Output Variation
- Internal Overcurrent-Limiting Circuitry
- Internal Thermal-Overload Protection
- Internal Overvoltage Protection

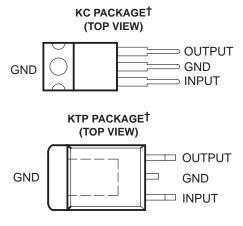
description

The TL2217-285 is a low-dropout (1 V) fixed-voltage regulator specifically designed for small computer systems interface (SCSI) alternative 2 active signal termination. The TL2217-285 1-V maximum dropout ensures compatibility with existing SCSI systems, while providing a wide TERMPWR voltage range. At the same time, the $\pm 1.5\%$ initial tolerance on its 2.85-V output voltage ensures a tighter line-driver current tolerance, thereby increasing system noise margin.

The fixed 2.85-V output voltage of TL2217-285 supports the SCSI alternative 2 termination standard, while reducing system power consumption. The 1-V maximum dropout voltage brings increased TERMPWR isolation, making the device ideal for battery-powered systems. The TL2217-285, with internal current limiting, overvoltage protection, ESD protection, and thermal protection, offers designers enhanced system protection and reliability.



HEAT SINK – These pins have an internal resistive connection to ground and should be grounded or electrically isolated.



† The GND terminal is in electrical contact with the mounting base.

When configured as a SCSI active terminator, the TL2217-285 low-dropout regulator eliminates the $220-\Omega$ and $330-\Omega$ resistors required for each transmission line with a passive termination scheme, reducing significantly the continuous system-power drain. When placed in series with $110-\Omega$ resistors, the device matches the impedance level of the transmission cable and eliminates reflections.

The TL2217-285 is characterized for operation over the virtual junction temperature range of 0°C to 125°C.



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AVAILABLE OPTIONS

		PACKAGED DEVICES	6	CHIP
TJ	PLASTIC POWER (KC)	PLASTIC FLANGE MOUNT (KTP)	SURFACE MOUNT (PW)	FORM (Y)
0°C to 125°C	TL2217-285KC	TL22I7-285KTP	TL22I7-285PWR	TL2217-285Y

The KTP and PW packages are only available taped and reeled. Add the suffix R to the device type (e.g., TL2217–285KTPR). Chip forms are tested at 25°C.

absolute maximum ratings over operating virtual junction temperature range (unless otherwise noted) †

Continuous input voltage, V ₁	7.5 V
Operating virtual junction temperature range, T _J	. −55°C to 150°C
Package thermal impedance, θ _{JA} (see Notes 1 and 2): KC package	22°C/W
KTP package	28°C/W
PW package	83°C/W
Lead temperature 1,6 mm (1/16 inch) from case for 60 seconds	260°C
Storage temperature range, T _{stg}	. −65°C to 150°C

[†] Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

- NOTES: 1. Maximum power dissipation is a function of T_J(max), θ_JA, and T_A. The maximum allowable power dissipation at any allowable ambient temperature is P_D = (T_J(max) T_A)/θ_JA. Operating at the absolute maximum T_J of 150°C can impact reliability. Due to variations in individual device electrical characteristics and thermal resistance, the built-in thermal overload protection may be activated at power levels slightly above or below the rated dissipation.
 - 2. The package thermal impedance is calculated in accordance with JESD 51, except for through-hole packages, which use a trace length of zero.

recommended operating conditions

		MIN	MAX	UNIT
Input voltage, V _I		3.85	5.5	V
Output current, IO			500	mA
Operating virtual junction temperature range, TJ	TL2217–285	0	125	°C



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electrical characteristics over recommended operating conditions, $V_I = 4.5 \text{ V}$, $I_O = 500 \text{ mA}$, $T_J = 25^{\circ}\text{C}$ (unless otherwise noted)

PARAMETER		TEST CONDITIONS [†]		TL2217-285			LINUT
PARAMETER	Į			MIN	TYP	MAX	UNIT
Output voltage	lo - 20 mA to 500 mA	$I_O = 20 \text{ mA to } 500 \text{ mA}, V_I = 3.85 \text{ V to } 5.5 \text{ V}$	T _J = 25°C	2.81	2.85	2.89	V
	10 = 20 mA to 500 mA,		T _J = 0°C to 125°C	2.765		2.935	
Input voltage regulation	V _I = 3.85 V to 5.5 V	V _I = 3.85 V to 5.5 V			5	15	mV
Ripple rejection	f = 120Hz,	V _{ripple} = 1 V _{PP}			-62		dB
Output voltage regulation	I _O = 20 mA to 500 mA				5	30	mV
Output noise voltage	f = 10 Hz to 100 kHz				500		μV
Dropout voltage						1	V
Bias current	IO = 0				2	5	
	I _O = 27 mA, equivalent	I _O = 27 mA, equivalent 1 line asserted			3	6	mA
	I _O = 500 mA, equivalent 18 lines asserted (8 bit)			26	49		

The Pulse-testing techniques are used to maintain the virtual junction temperature as close to the ambient temperature as possible. Thermal effects must be taken into account separately. All characteristics are measured with a 0.1- μ F capacitor across the input and a 22- μ F tantalum capacitor with equivalent series resistance of 1.5 Ω on the output.

electrical characteristics over recommended operating conditions, $V_I = 4.5 \text{ V}$, $I_O = 500 \text{ mA}$, $T_J = 25 ^{\circ}\text{C}$ (unless otherwise noted)

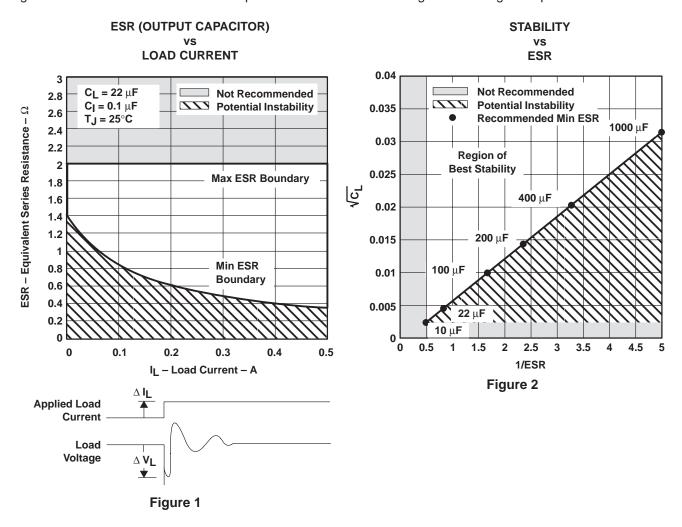
PARAMETER	TEST CONDITIONS!	TL2217-285Y			UNIT	
PARAMETER	TEST CONDITIONS [†]	MIN	TYP	MAX	UNII	
Output voltage	$I_O = 20 \text{ mA to } 500 \text{ mA}, V_I = 3.85 \text{ V to } 5.5 \text{ V}$	2.81	2.85	2.89	V	
Input voltage regulation	V _I = 3.85 V to 5.5 V		5	15	mV	
Ripple rejection	$f = 120 \text{ Hz},$ $V_{ripple} = 1 \text{ Vpp}$		-62		dB	
Output voltage regulation	I _O = 20 mA to 500 mA		5	30	mV	
Output noise voltage	f = 10 Hz to 100 kHz		500		μV	
Dropout voltage	I _O = 500 mA			1	V	
	IO = 0		2	5	mA	
Bias current	I _O = 27 mA, equivalent 1 line asserted		3	6		
	I _O = 500 mA, equivalent 18 lines asserted (8 bit)		26	49		

[†] Pulse-testing techniques are used to maintain the virtual junction temperature as close to the ambient temperature as possible. Thermal effects must be taken into account separately. All characteristics are measured with a 0.1- μ F capacitor across the input and a 22- μ F tantalum capacitor with equivalent series resistance of 1.5 Ω on the output.



COMPENSATION-CAPACITOR SELECTION INFORMATION

The TL2217-285 is a low-dropout regulator. This means that the capacitance loading is important to the performance of the regulator because it is a vital part of the control loop. The capacitor value and the equivalent series resistance (ESR) both affect the control loop and must be defined for the load range and the temperature range. Figure 3 and Figure 4 can be used to establish the capacitance value and ESR range for best regulator performance.





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APPLICATION INFORMATION

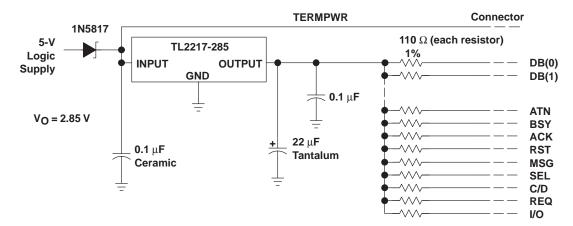


Figure 3. Typical Application Schematic



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